



PHPT60610NY

60 V, 10 A NPN high power bipolar transistor

15 January 2019

Product data sheet

1. General description

NPN high power bipolar transistor in a SOT669 (LFAK56) Surface-Mounted Device (SMD) power plastic package.

PNP complement: PHPT60610PY

2. Features and benefits

- High thermal power dissipation capability
- High temperature applications up to 175 °C
- Reduced Printed Circuit Board (PCB) requirements comparing to transistors in DPAK
- High energy efficiency due to less heat generation
- AEC-Q101 qualified.

3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- Backlighting applications
- Motor drive
- Relay replacement

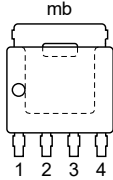
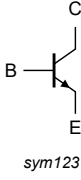
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	60	V
I_C	collector current		-	-	10	A
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms	-	-	20	A
R_{CEsat}	collector-emitter saturation resistance	$I_C = 10$ A; $I_B = 1$ A; $t_p \leq 300$ μ s; pulsed; $\delta \leq 0.02$; $T_{amb} = 25$ °C	-	25	36	m Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	 <p>LFPAK56; Power-SO8 (SOT669)</p>	
2	E	emitter		
3	E	emitter		
4	B	base		
mb	C	collector		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PHPT60610NY	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669

7. Marking

Table 4. Marking codes

Type number	Marking code
PHPT60610NY	0610NAB

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V_{CBO}	collector-base voltage	open emitter	-	60	V	
V_{CEO}	collector-emitter voltage	open base	-	60	V	
V_{EBO}	emitter-base voltage	open collector	-	7	V	
I_C	collector current		-	10	A	
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms	-	20	A	
I_B	base current		-	1.5	A	
I_{BM}	peak base current	single pulse; $t_p \leq 1$ ms	-	2	A	
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	1.5	W
			[2]	-	3.7	W
			[3]	-	5	W
			[4]	-	25	W
T_j	junction temperature		-	175	°C	
T_{amb}	ambient temperature		-55	175	°C	
T_{stg}	storage temperature		-65	175	°C	

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated and mounting pad for collector 6 cm².
- [3] Device mounted on a ceramic PCB; Al₂O₃, standard footprint.
- [4] Power dissipation from junction to mounting base.

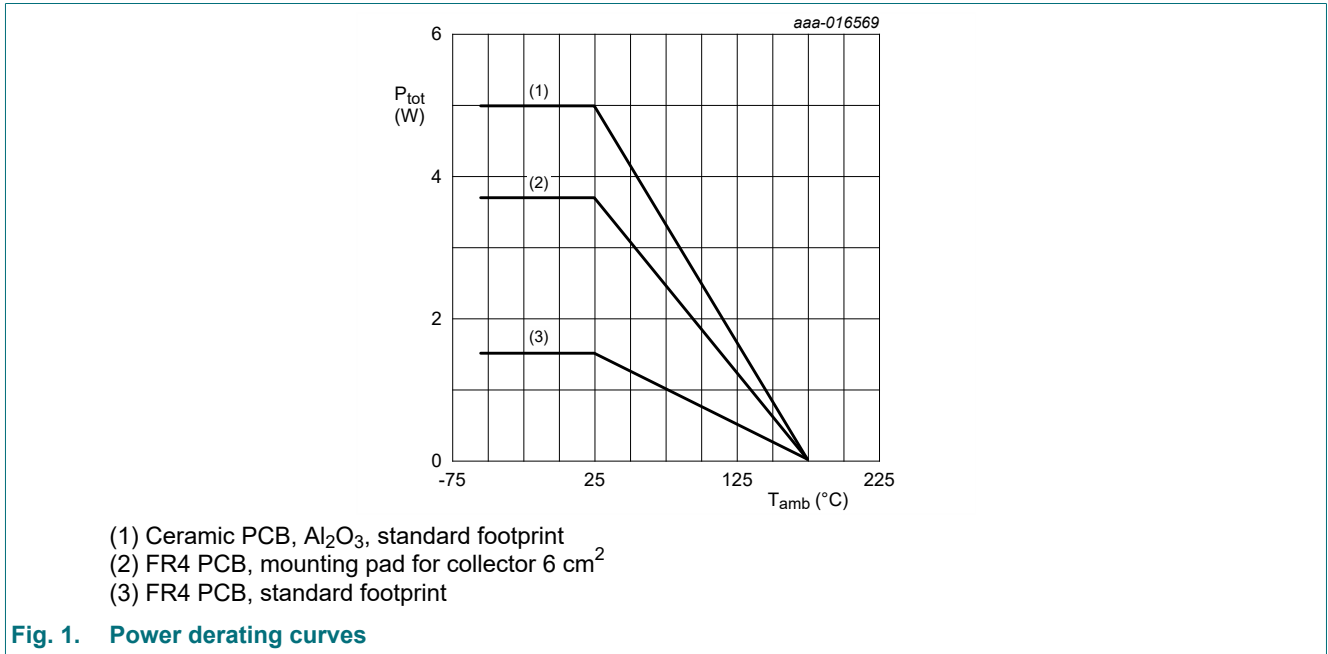


Fig. 1. Power derating curves

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	100	K/W
			[2]	-	-	41	K/W
			[3]	-	-	30	K/W
$R_{th(j-mb)}$	thermal resistance from junction to mounting base			-	-	6	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².
- [3] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

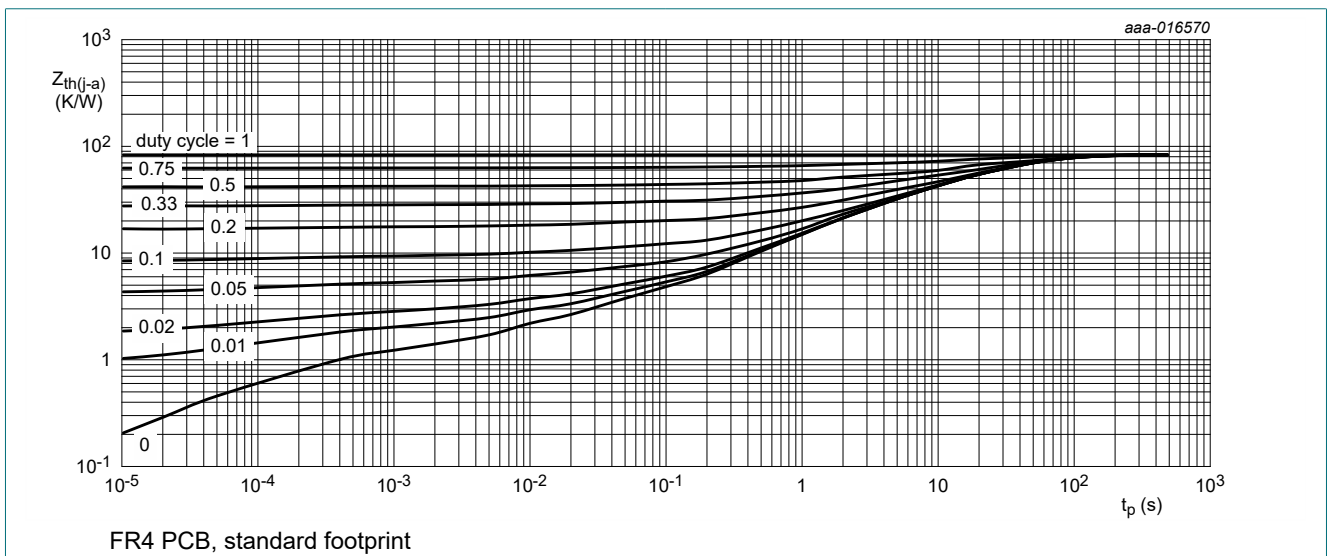


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

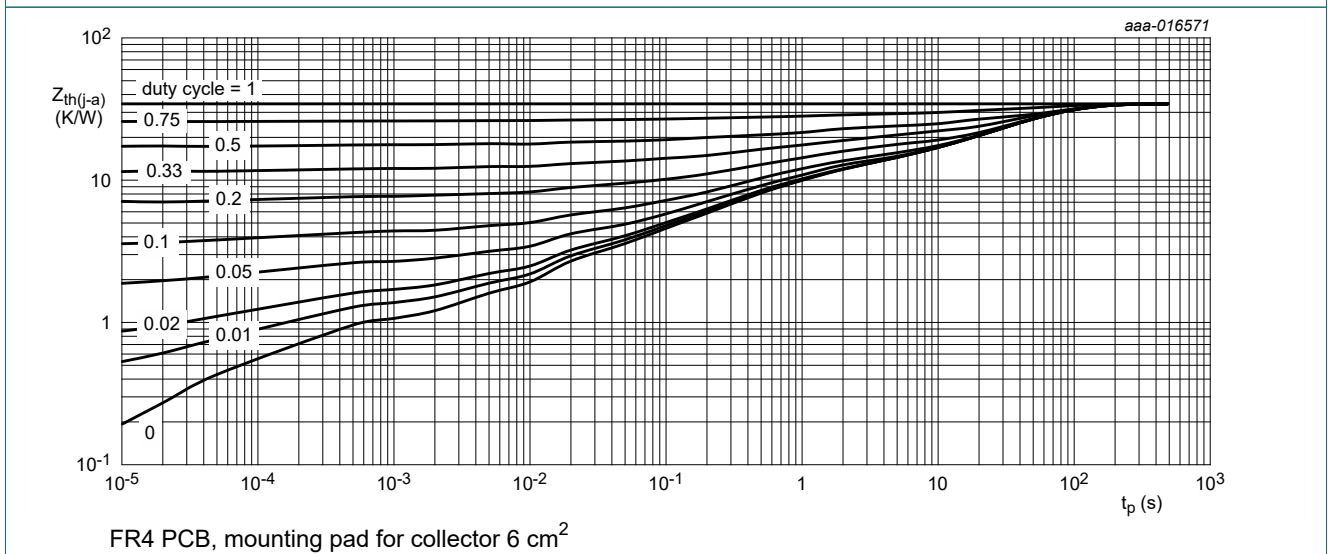
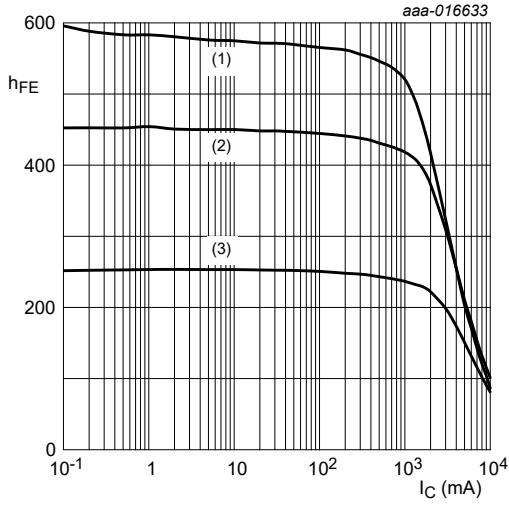


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

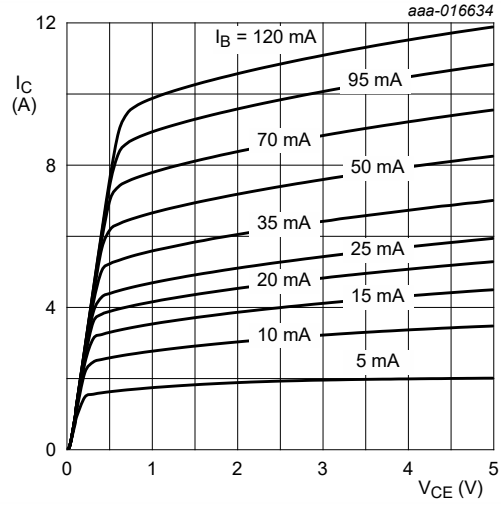
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = 48\text{ V}; I_E = 0\text{ A}; T_{amb} = 25\text{ °C}$	-	-	100	nA
		$V_{CB} = 48\text{ V}; I_E = 0\text{ A}; T_J = 150\text{ °C}$	-	-	50	μA
I_{CES}	collector-emitter cut-off current	$V_{CE} = 48\text{ V}; V_{BE} = 0\text{ V}; T_{amb} = 25\text{ °C}$	-	-	100	nA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 7\text{ V}; I_C = 0\text{ A}; T_{amb} = 25\text{ °C}$	-	-	100	nA
h_{FE}	DC current gain	$V_{CE} = 2\text{ V}; I_C = 500\text{ mA}; T_{amb} = 25\text{ °C}$	240	410	-	
		$V_{CE} = 2\text{ V}; I_C = 1\text{ A}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ °C}$	210	400	-	
		$V_{CE} = 2\text{ V}; I_C = 5\text{ A}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ °C}$	100	200	-	
		$V_{CE} = 2\text{ V}; I_C = 10\text{ A}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ °C}; \text{pulsed}$	50	100	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 1\text{ A}; I_B = 50\text{ mA}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ °C}; \text{pulsed}$	-	30	40	mV
		$I_C = 5\text{ A}; I_B = 500\text{ mA}; t_p \leq 300\text{ }\mu\text{s}; \text{pulsed}; \delta \leq 0.02; T_{amb} = 25\text{ °C}$	-	115	160	mV
		$I_C = 10\text{ A}; I_B = 1\text{ A}; t_p \leq 300\text{ }\mu\text{s}; \text{pulsed}; \delta \leq 0.02; T_{amb} = 25\text{ °C}$	-	250	360	mV
R_{CEsat}	collector-emitter saturation resistance		-	25	36	m Ω
V_{BEsat}	base-emitter saturation voltage	$I_C = 1\text{ A}; I_B = 50\text{ mA}; t_p \leq 300\text{ }\mu\text{s}; \text{pulsed}; \delta \leq 0.02; T_{amb} = 25\text{ °C}$	-	-	0.95	V
		$I_C = 5\text{ A}; I_B = 500\text{ mA}; t_p \leq 300\text{ }\mu\text{s}; \text{pulsed}; \delta \leq 0.02; T_{amb} = 25\text{ °C}$	-	-	1.2	V
		$I_C = 10\text{ A}; I_B = 1\text{ A}; t_p \leq 300\text{ }\mu\text{s}; \text{pulsed}; \delta \leq 0.02; T_{amb} = 25\text{ °C}$	-	-	1.4	V
V_{BEon}	base-emitter turn-on voltage	$V_{CE} = 2\text{ V}; I_C = 500\text{ mA}; T_{amb} = 25\text{ °C}$	-	-	0.8	V
t_d	delay time	$V_{CC} = 12.5\text{ V}; I_C = 5\text{ A}; I_{B(on)} = 250\text{ mA}; I_{B(off)} = -250\text{ mA}; T_{amb} = 25\text{ °C}$	-	20	-	ns
t_r	rise time		-	180	-	ns
t_{on}	turn-on time		-	200	-	ns
t_s	storage time		-	340	-	ns
t_f	fall time		-	165	-	ns
t_{off}	turn-off time		-	505	-	ns
f_T	transition frequency		$V_{CE} = 10\text{ V}; I_C = 500\text{ mA}; f = 100\text{ MHz}; T_{amb} = 25\text{ °C}$	-	140	-
C_c	collector capacitance	$V_{CB} = 10\text{ V}; I_E = 0\text{ A}; i_e = 0\text{ A}; f = 1\text{ MHz}; T_{amb} = 25\text{ °C}$	-	50	-	pF



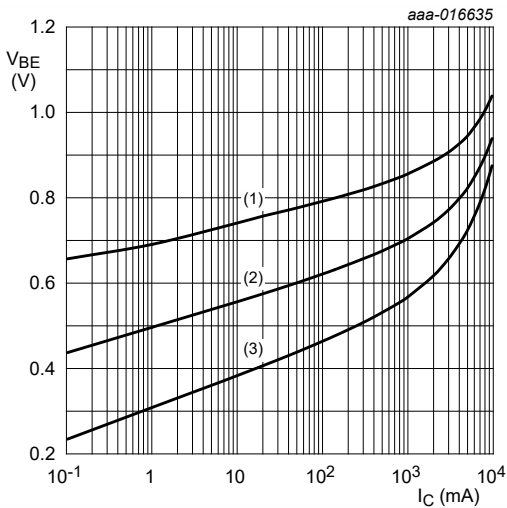
$V_{CE} = 2\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig. 4. DC current gain as a function of collector current; typical values



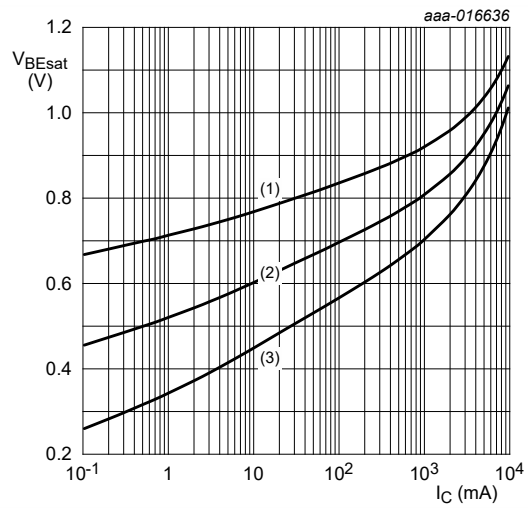
$T_{amb} = 25\text{ °C}$

Fig. 5. Collector current as a function of collector-emitter voltage; typical values



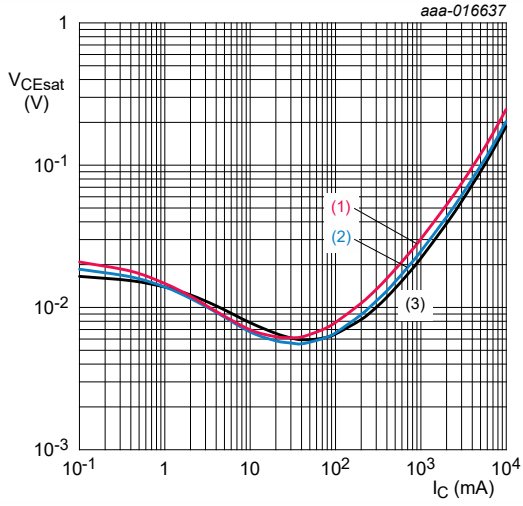
$V_{CE} = 2\text{ V}$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig. 6. Base-emitter voltage as a function of collector current; typical values



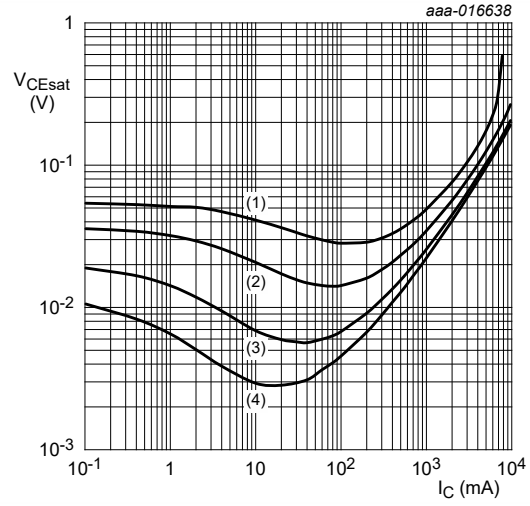
$I_C/I_B = 20$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values



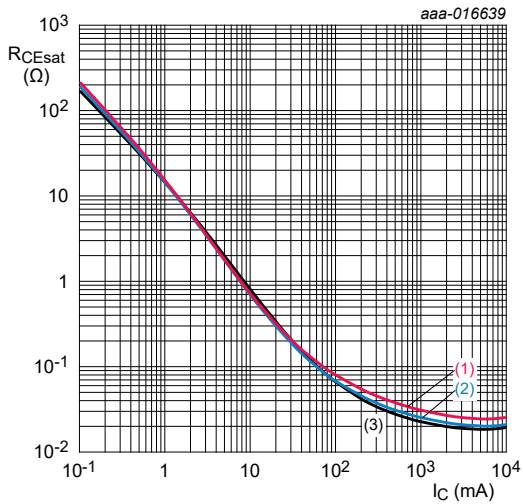
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values



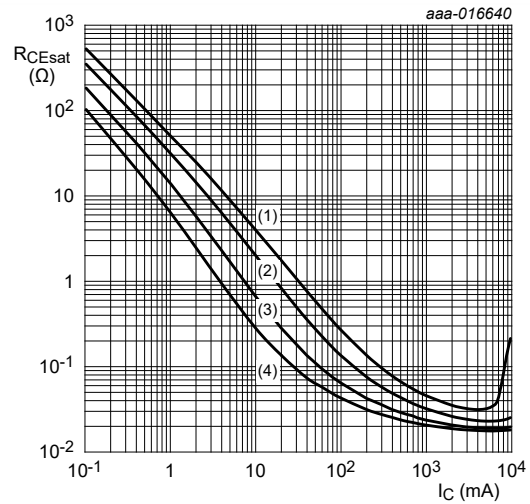
$T_{amb} = 25\text{ °C}$
 (1) $I_C/I_B = 100$
 (2) $I_C/I_B = 50$
 (3) $I_C/I_B = 20$
 (4) $I_C/I_B = 10$

Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values



$T_{amb} = 25\text{ °C}$
 (1) $I_C/I_B = 100$
 (2) $I_C/I_B = 50$
 (3) $I_C/I_B = 20$
 (4) $I_C/I_B = 10$

Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

11. Test information

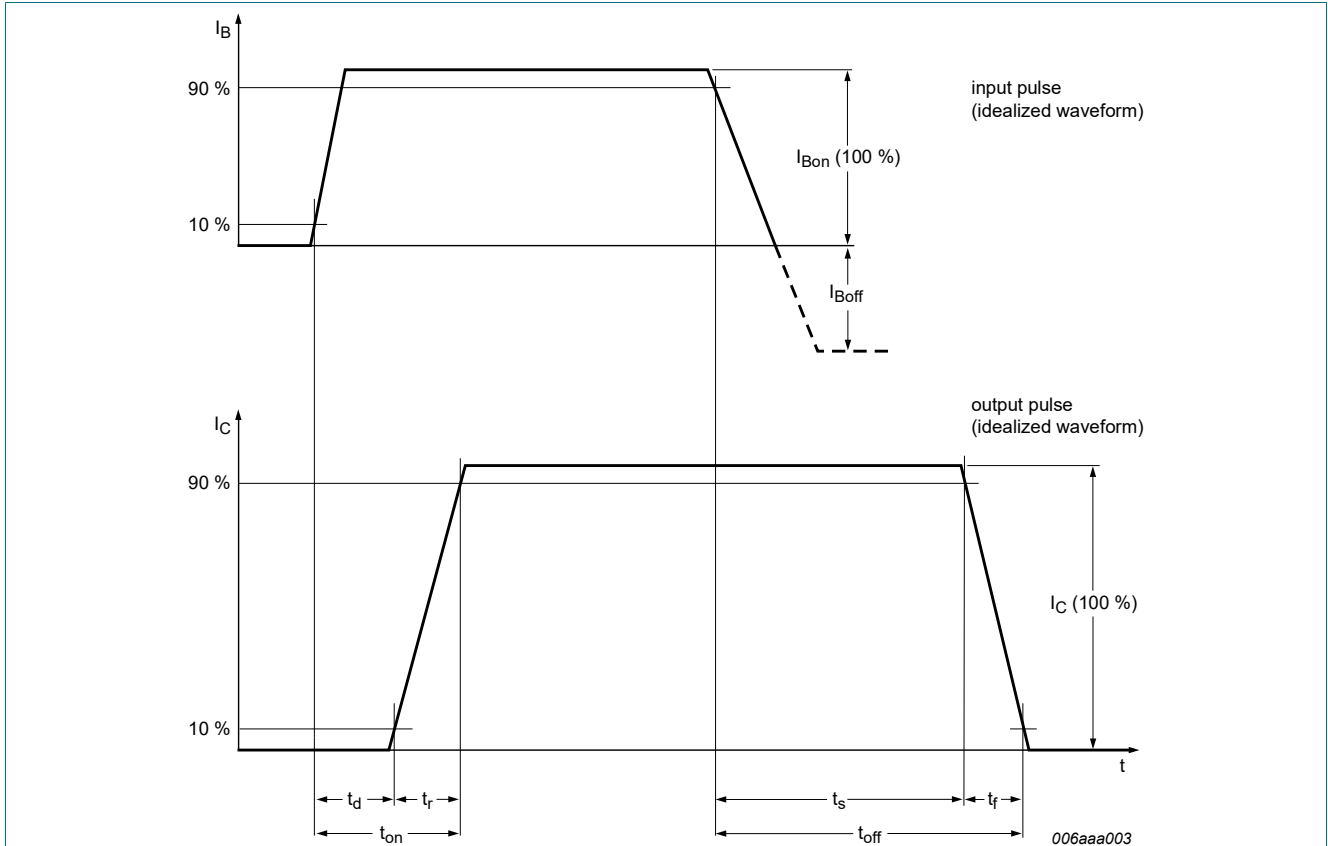


Fig. 12. BISS transistor switching time definition

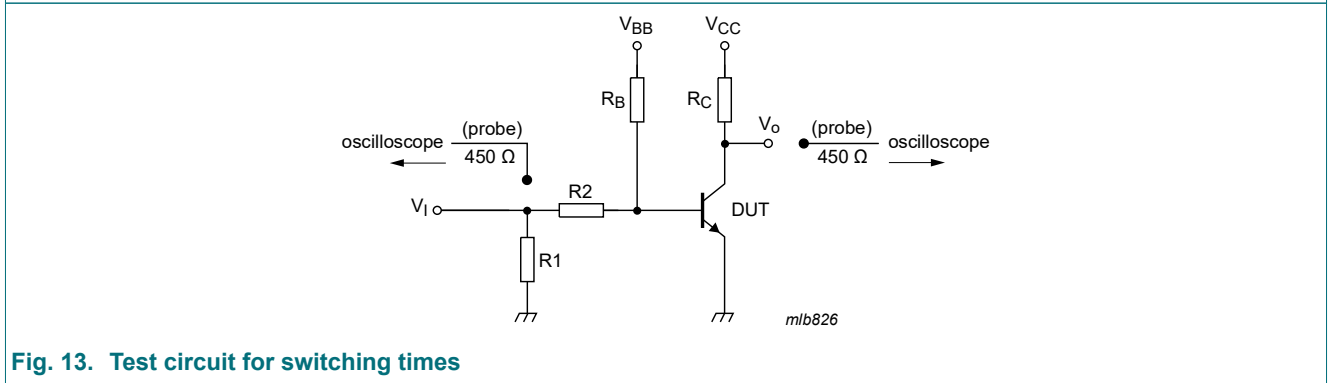


Fig. 13. Test circuit for switching times

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline

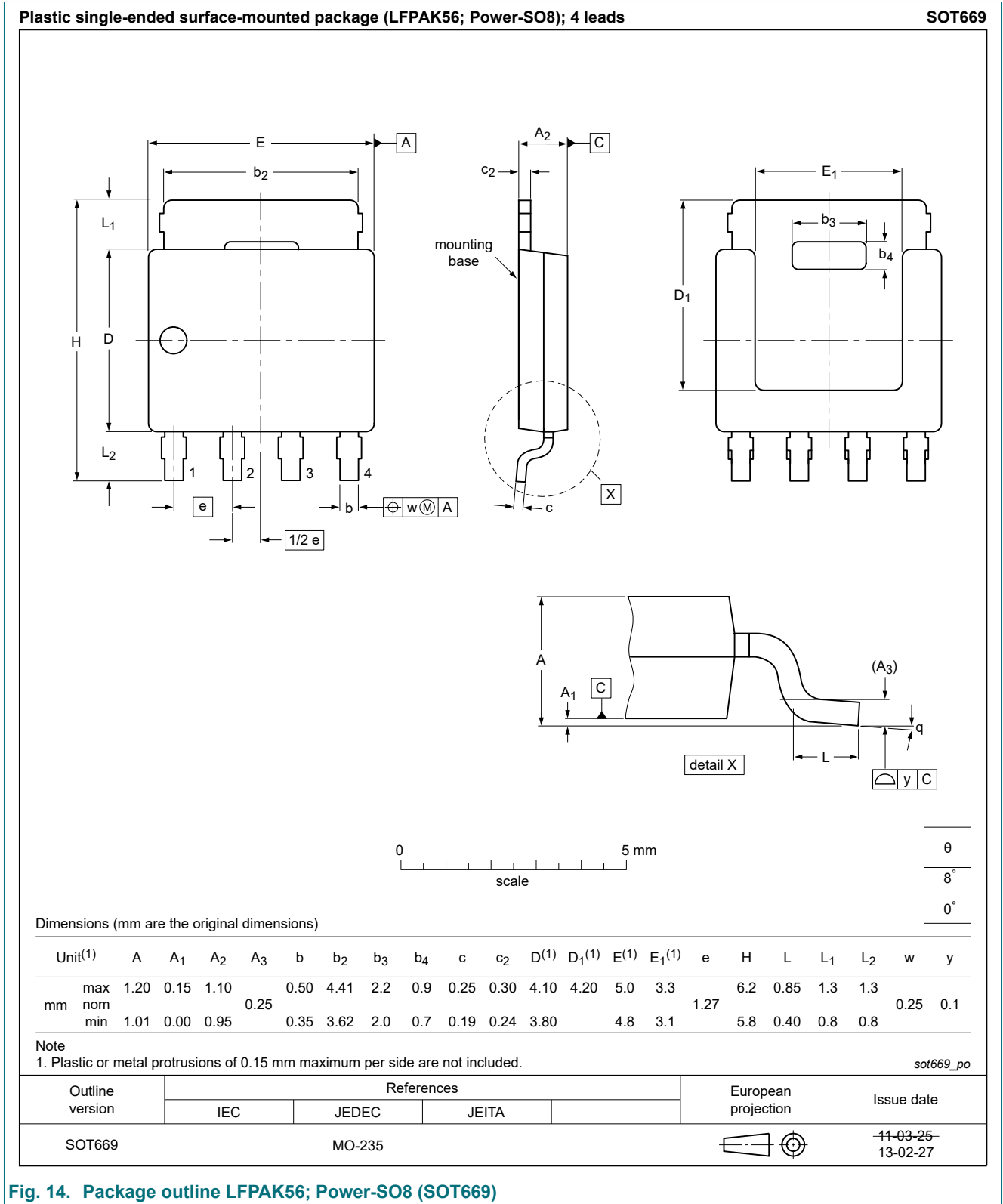


Fig. 14. Package outline LFAK56; Power-SO8 (SOT669)

13. Soldering

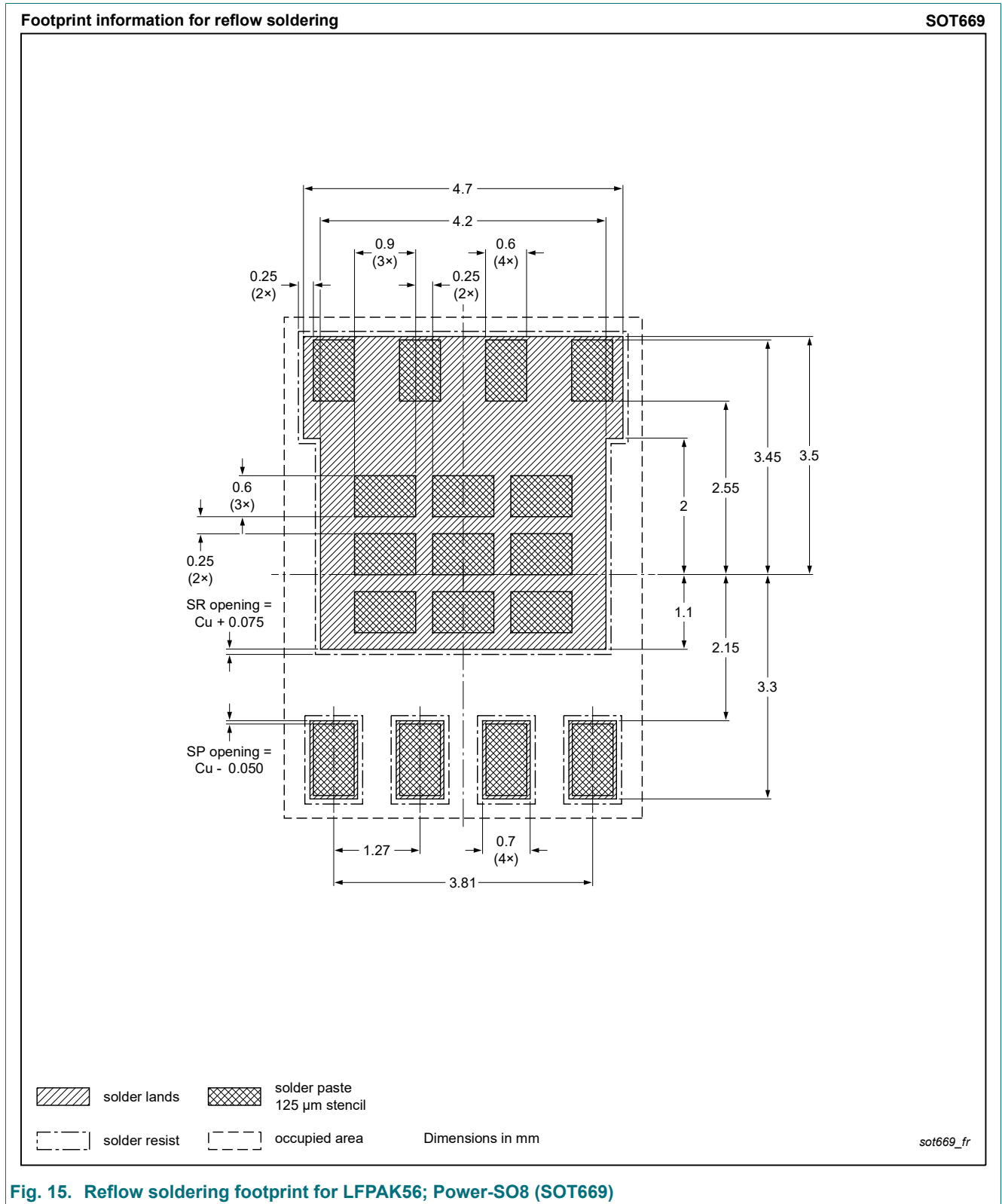


Fig. 15. Reflow soldering footprint for LFPAK56; Power-SO8 (SOT669)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PHPT60610NY v.2	20190115	Product data sheet	-	PHPT60610NY v.1
Modifications:	• Typo at figures 2 and 3: unit corrected from ns to s at x-scale			
PHPT60610NY v.1	20150527	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Contents

1. General description.....	1
2. Features and benefits.....	1
3. Applications.....	1
4. Quick reference data.....	1
5. Pinning information.....	2
6. Ordering information.....	2
7. Marking.....	2
8. Limiting values.....	3
9. Thermal characteristics.....	4
10. Characteristics.....	5
11. Test information.....	8
12. Package outline.....	9
13. Soldering.....	10
14. Revision history.....	11
15. Legal information.....	12

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